

SCR

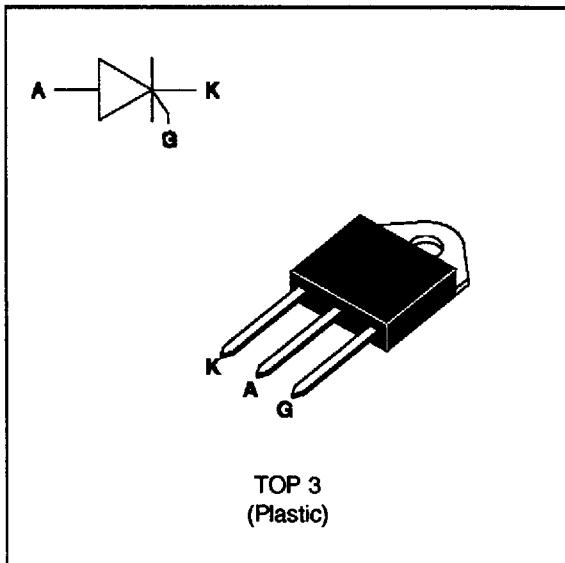
FEATURES

- HIGH SURGE CAPABILITY
- HIGH ON-STATE CURRENT
- HIGH STABILITY AND RELIABILITY
- BTW 69 Serie :
INSULATED VOLTAGE = 2500V(RMS)
(UL RECOGNIZED : E81734)

DESCRIPTION

The BTW 69 (N) Family of Silicon Controlled Rectifiers uses a high performance glass passivated technology.

This general purpose Family of Silicon Controlled Rectifiers is designed for power supplies up to 400Hz on resistive or inductive load.


ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
I _T (RMS)	RMS on-state current (180° conduction angle)	BTW 69 BTW 69 N	T _c =70°C T _c =75°C	50 55	A
I _T (AV)	Average on-state current (180° conduction angle, single phase circuit)	BTW 69 BTW 69 N	T _c =70°C T _c =75°C	32 35	A
I _{TSM}	Non repetitive surge peak on-state current (T _j initial = 25°C)		tp=8.3 ms	525	A
			tp=10 ms	500	
I _{2t}	I _{2t} value	tp=10 ms	1250	A ² s	
dI/dt	Critical rate of rise of on-state current Gate supply : I _G = 100 mA dI _G /dt = 1 A/μs		100	A/μs	
T _{stg} T _j	Storage and operating junction temperature range		- 40 to + 150 - 40 to + 125	°C °C	
T _I	Maximum lead temperature for soldering during 10 s at 4.5 mm from case		230		°C

Symbol	Parameter	BTW 69		BTW 69 / BTW 69 N				Unit
		200	400	600	800	1000	1200	
V _{DRM} V _{RRM}	Repetitive peak off-state voltage T _j = 125 °C	200	400	600	800	1000	1200	V

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th} (j-a)	Junction to ambient	50	°C/W
R _{th} (j-c) DC	Junction to case for DC	BTW 69	0.9
		BTW 69 N	0.8

GATE CHARACTERISTICS (maximum values)

P_G (AV) = 1W P_{GM} = 40W (t_p = 20 μs) I_{FGM} = 8A (t_p = 20 μs) V_{RGM} = 5 V.

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions	Value		Unit
		BTW 69	BTW 69 N	
I _{GT}	V _D =12V (DC) R _L =33Ω	T _j =25°C	MAX	80 mA
V _{GT}	V _D =12V (DC) R _L =33Ω	T _j =25°C	MAX	1.5 V
V _{GD}	V _D =V _{DRM} R _L =3.3kΩ	T _j = 125°C	MIN	0.2 V
t _{gt}	V _D =V _{DRM} I _G = 200mA dI _G /dt = 1.5A/μs	T _j =25°C	TYP	2 μs
I _L	I _G = 1.2 I _{GT}	T _j =25°C	TYP	50 mA
I _H	I _T = 500mA gate open	T _j =25°C	MAX	150 mA
V _{TM}	BTW 69 I _{TM} = 100A BTW 69 N I _{TM} = 110A t _p = 380μs	T _j =25°C	MAX	1.9 2.0 V
I _{DRM} I _{RRM}	V _{DRM} Rated V _{RRM} Rated	T _j =25°C	MAX	0.02 mA
		T _j = 125°C		6
dV/dt	Linear slope up to V _D =67%V _{DRM} gate open	V _{DRM} ≤ 800V V _{DRM} ≥ 1000V	T _j = 125°C	500 250 V/μs
t _q	V _D =67%V _{DRM} I _{TM} = 110A V _R = 75V dI _{TM} /dt=30 A/μs	dV _D /dt= 20V/μs	T _j = 125°C	TYP 100 μs

Package	$I_T(\text{RMS})$	V_{DRM} / V_{RRM}	Sensitivity Specification	
			A	B
BTW 69 (Insulated)	50	200	X	
		400	X	
		600	X	
		800	X	
		1000	X	
		1200	X	
BTW 69 N (Uninsulated)	55	600	X	
		800	X	
		1000	X	
		1200	X	

Fig.1 : Maximum average power dissipation versus average on-state current (BTW 69).

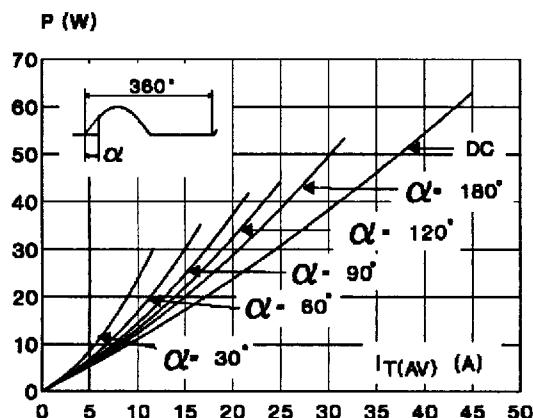


Fig.3 : Maximum average power dissipation versus average on-state current (BTW 69 N).

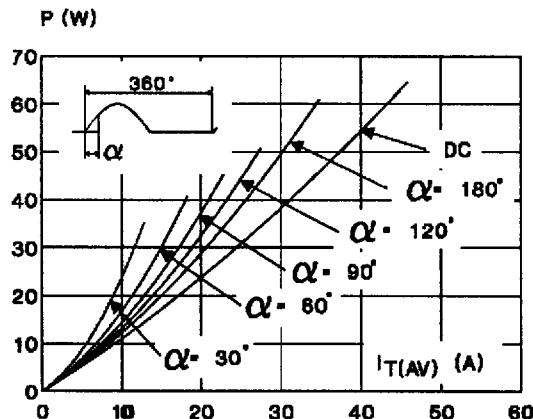


Fig.2 : Correlation between maximum average power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTW 69).

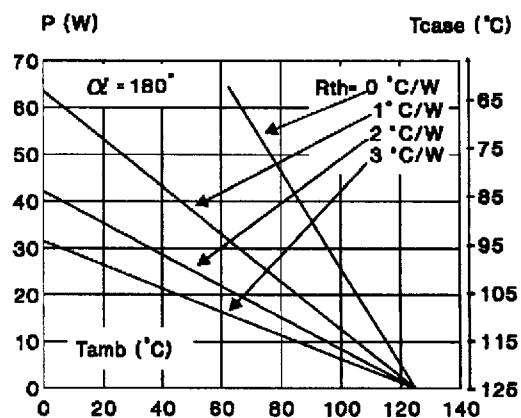
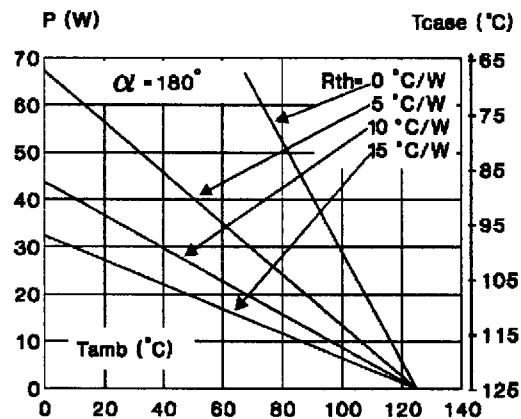


Fig.4 : Correlation between maximum average power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTW 69 N).



BTW 69 (N)

Fig.5 : Average on-state current versus case temperature (BTW 69).

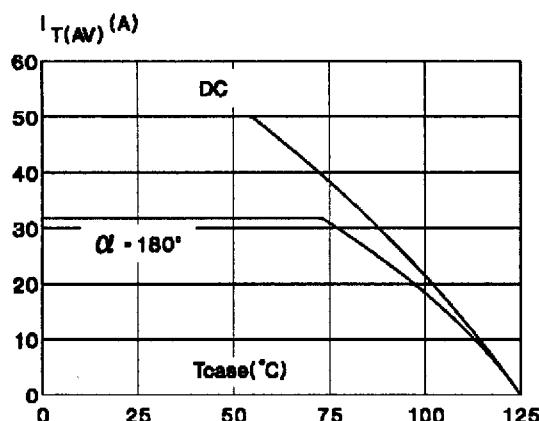


Fig.6 : Average on-state current versus case temperature (BTW 69 N).

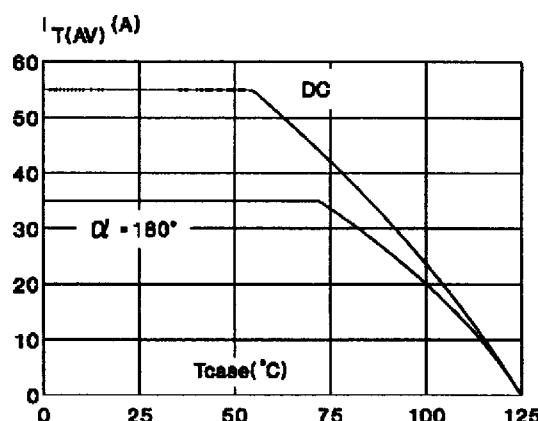


Fig.7 : Relative variation of thermal impedance versus pulse duration.

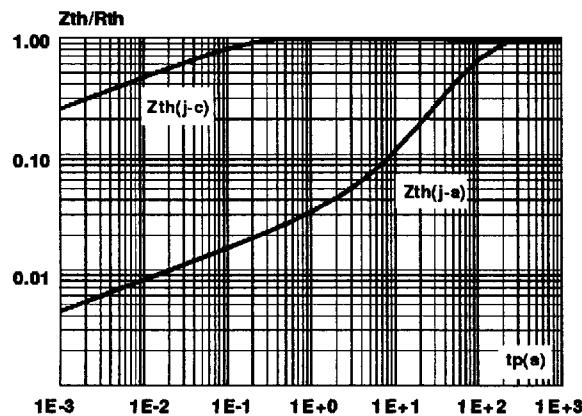


Fig.8 : Relative variation of gate trigger current versus junction temperature.

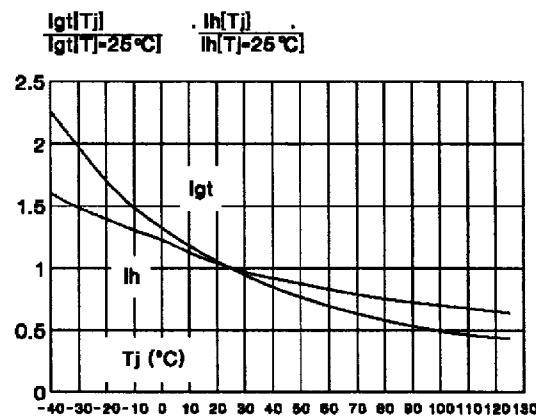


Fig.9 : Non repetitive surge peak on-state current versus number of cycles.

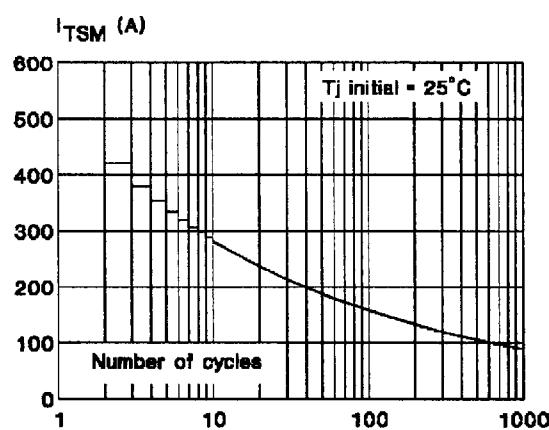


Fig.10 : Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms, and corresponding value of I^2t .

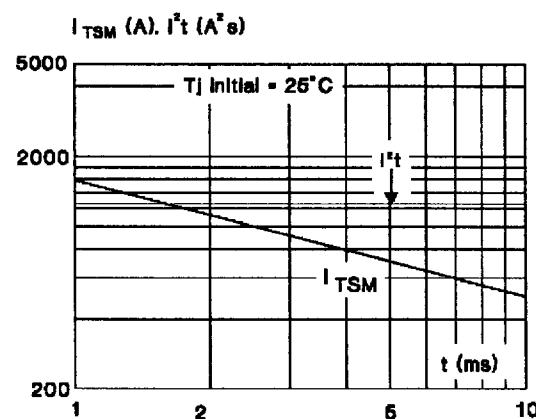
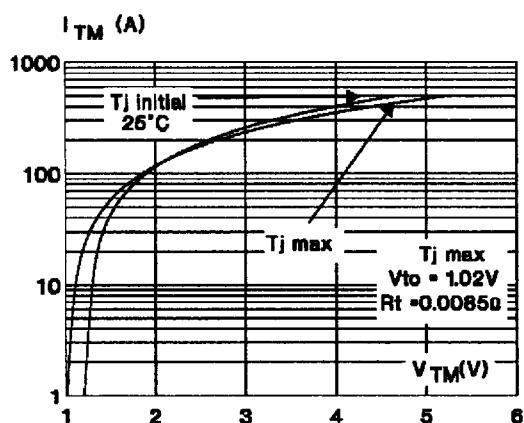


Fig11 : On-state characteristics (maximum values).



PACKAGE MECHANICAL DATA

TOP 3 Plastic

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	15.10	15.50	0.594	0.611
B	20.70	21.10	0.814	0.831
C	14.30	15.60	0.561	0.615
D	16.10	16.50	0.632	0.650
G	3.40	-	0.133	-
H	4.40	4.60	0.173	0.182
I	4.08	4.17	0.161	0.164
J	1.45	1.55	0.057	0.062
L	0.50	0.70	0.019	0.028
M	2.70	2.90	0.106	0.115
N	5.40	5.65	0.212	0.223
P	1.20	1.40	0.047	0.056

Cooling method : C
 Marking : type number
 Weight : 4.7 g

Recommended torque value : 0.8 m.N.
 Maximum torque value : 1 m.N.

Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.

SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectronics.

© 1995 SGS-THOMSON Microelectronics - Printed in Italy - All rights reserved.

SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [SCRs](#) category:

Click to view products by [STMicroelectronics](#) manufacturer:

Other Similar products are found below :

[NTE5428](#) [T1500N16TOF](#) [VT](#) [T880N16TOF](#) [TT162N16KOF-A](#) [TT162N16KOF-K](#) [TT330N16AOF](#) [VS-22RIA20](#) [VS-2N685](#) [057219R](#)
[T1190N16TOF](#) [VT](#) [T1220N22TOF](#) [VT](#) [T201N70TOH](#) [T700N22TOF](#) [T830N18TOF](#) [TT250N12KOF-K](#) [VS-110RKI40](#) [NTE5427](#) [NTE5442](#)
[T2160N28TOF](#) [VT](#) [TT251N16KOF-K](#) [VS-22RIA100](#) [VS-16RIA40](#) [TD250N16KOF-A](#) [VS-ST110S16P0](#) [T930N36TOF](#) [VT](#) [T2160N24TOF](#)
[VT](#) [T1190N18TOF](#) [VT](#) [T1590N28TOF](#) [VT](#) [2N1776A](#) [T590N14TOF](#) [NTE5375](#) [NTE5460](#) [NTE5481](#) [NTE5512](#) [NTE5514](#) [NTE5518](#)
[NTE5519](#) [NTE5529](#) [NTE5553](#) [NTE5555](#) [NTE5557](#) [NTE5567](#) [NTE5570](#) [NTE5572](#) [NTE5574](#) [NTE5576](#) [NTE5578](#) [NTE5579](#) [NTE5589](#)
[NTE5592](#)